

GP2S09/GP2S24/ GP2S26/GP2S27

Subminiature Photointerrupter

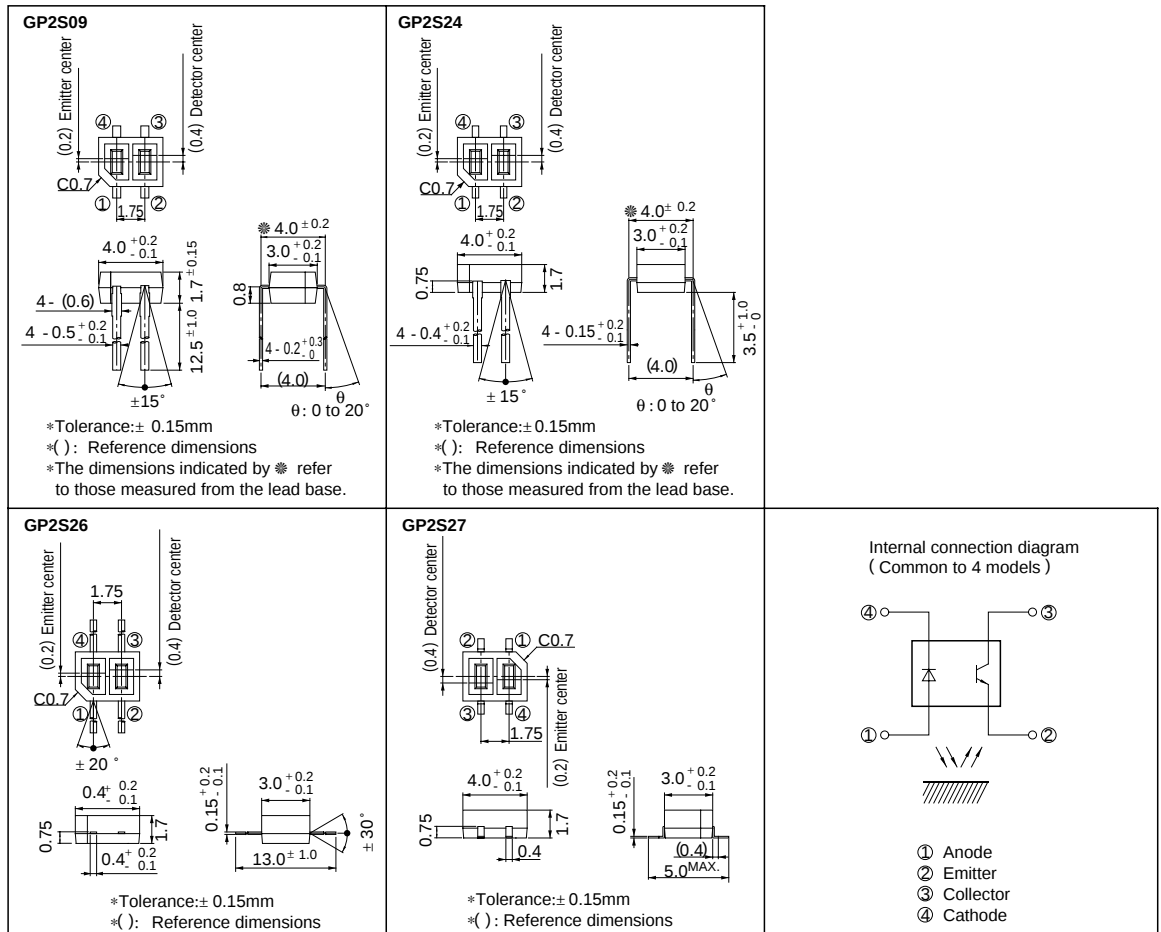
■ Features

1. Compact and thin
GP2S09: Compact DIP long lead type
GP2S24: Compact DIP type
GP2S26: Flat lead type
GP2S27: Mini-flat package type

2. Optimum detection distance: 0.6 to 0.8mm
3. Visible light cut-off type

■ Outline Dimensions

(Unit : mm)



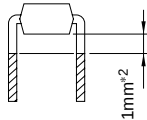
■ Absolute Maximum Ratings (Ta = 25°C)

Parameter		Symbol	Rating	Unit
Input	Forward current	IF	50	mA
	Reverse voltage	VR	6	V
	Power dissipation	P	75	mW
Output	Collector-emitter voltage	VCEO	35	V
	Emitter-collector voltage	VECO	6	V
	Collector current	IC	20	mA
	Collector power dissipation	PC	75	mW
	Total power dissipation	Ptot	100	mW
	Operating temperature	Topr	- 20 to + 85	°C
	Storage temperature	Tstg	- 40 to + 100	°C
	*1Soldering temperature	Tsol	260	°C

*1 Within 5 seconds (Soldering areas for each model are shown below)

GP2S09, GP2S24

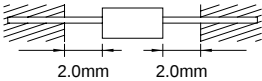
Soldering area:
The hatched area more than 1mm^{*2} away from the lower edge of package as shown in the figure below.



*2 GP2S09: 4mm

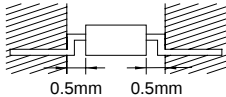
GP2S26

Soldering area:
The hatched area more than 2.0mm away from the both edges of package as shown in the figure below.



GP2S27

Soldering area
The hatched area more than 0.5mm away from the both edges of package as shown in the figure below.



■ Electro-optical Characteristics (Ta = 25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	VF	IF = 20mA	-	1.2	1.4	V
	Reverse current	IR	VR = 6V	-	-	10	μ A
Output	Collector dark current	ICEO	VCE = 20V	-	10 ⁻⁹	10 ⁻⁷	A
Transfer characteristics	*3Collector current	IC	IF = 4mA, VCE = 2V	20	45	120	μ A
	Response time	Rise time	VCE = 2V, IC = 100 μ A RL = 1kΩ , d = 1mm	-	20	100	μ s
		Fall time		-	20	100	μ s
	*4Leak current	I LEAK	IF = 4mA, VCE = 2V	-	-	0.1	μ A

*3 The condition and arrangement of the reflective object are shown below.

*4 Without reflective object

The ranking of collector current shall be classified into the following 6 ranks.

(GP2S09, GP2S24, GP2S26, GP2S27)

Rank	Collector-current IC (μ A)
*5A	20 to 42
B	34 to 71
C	58 to 120
A or B	20 to 71
B or C	34 to 120
A, B or C	20 to 120

*5 GP2S24 and GP2S26 and GP2S27 don't have A rank.

Test Condition and Arrangement for Collector Current

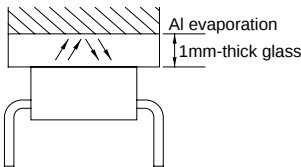


Fig. 1 Forward Current vs. Ambient Temperature

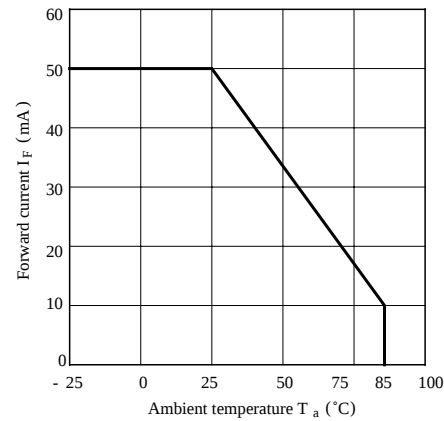


Fig. 2 Power Dissipation vs. Ambient Temperature

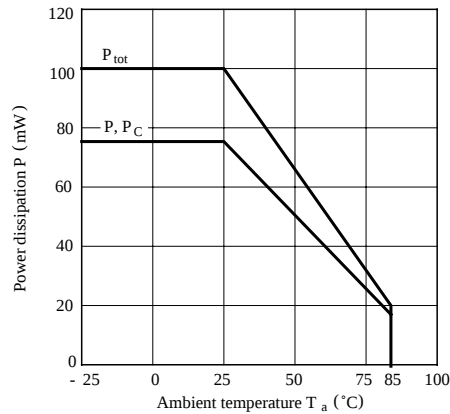


Fig. 3 Forward Current vs. Forward Voltage

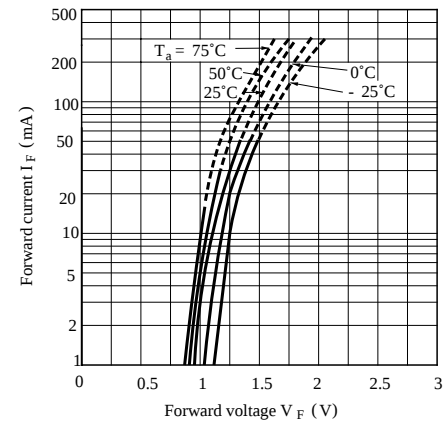


Fig. 4 Collector Current vs. Forward Current

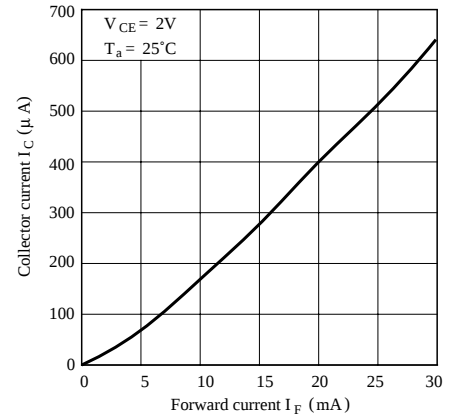


Fig. 5 Collector Current vs. Collector-Emitter Voltage

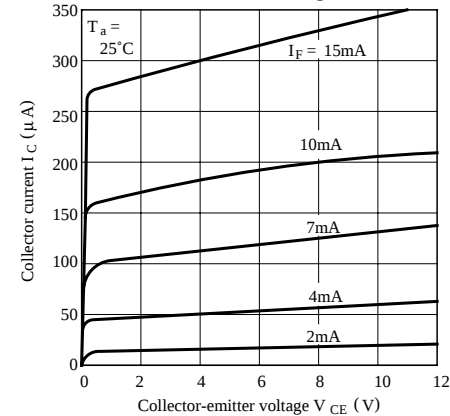


Fig. 6 Relative Collector Current vs. Ambient Temperature

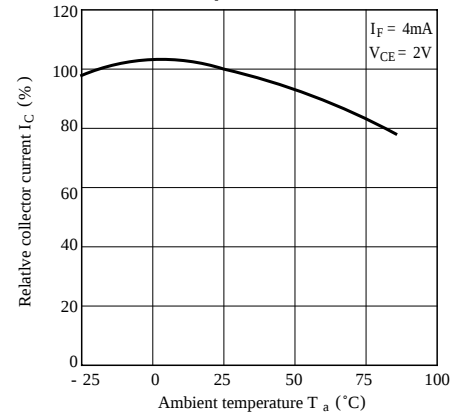


Fig. 7 Collector Dark Current vs. Ambient Temperature

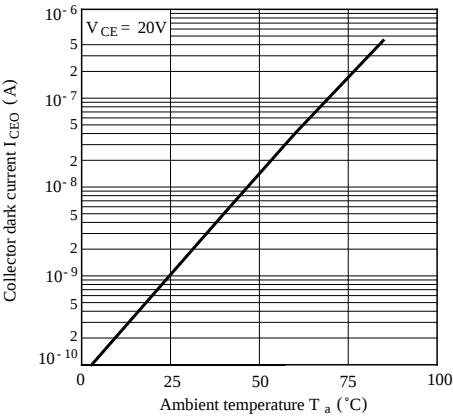


Fig. 8 Response Time vs. Load Resistance (GP2S09)

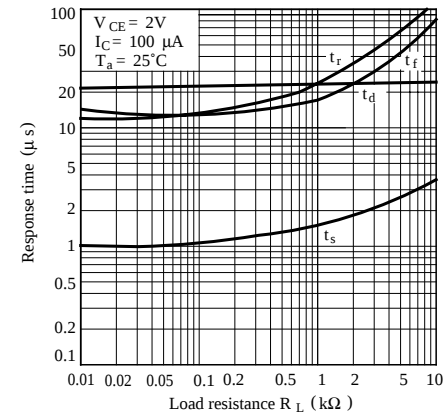


Fig. 9 Response Time vs. Load Resistance (GP2S24/ GP2S26/GP2S27)

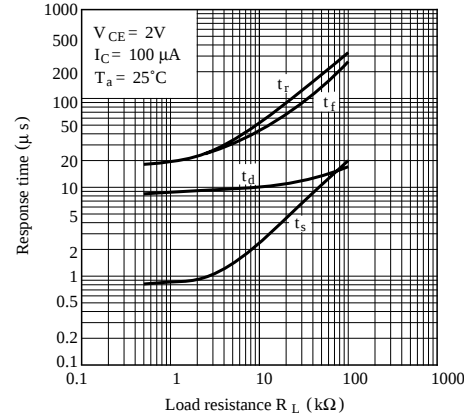
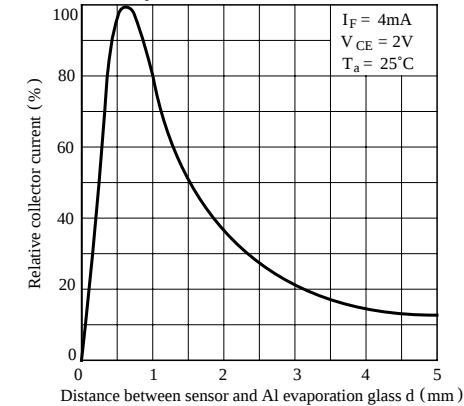


Fig.10 Relative Collector Current vs. Distance between Sensor and Al Evaporation Glass



Test Circuit for Response Time

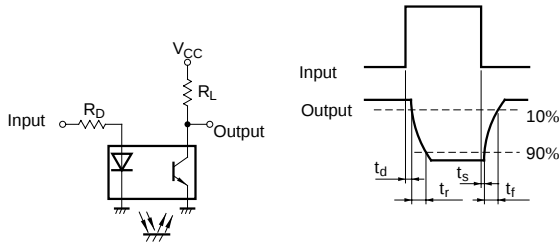


Fig.11 Relative Collector Current vs. Card Moving Distance (1)

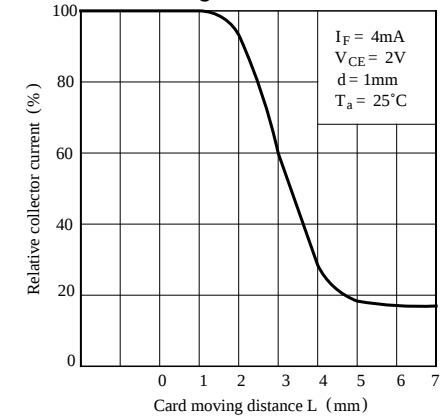
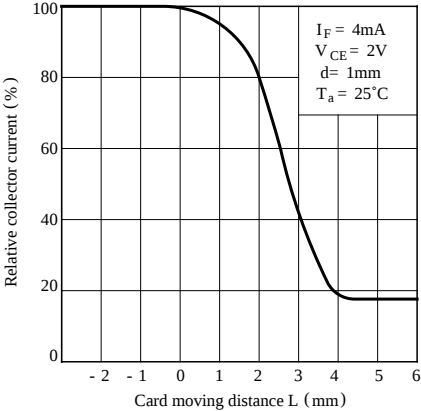


Fig.12 Relative Collector Current vs. Card Moving Distance (2)



Test Condition for Distance & Detecting Position Characteristics (EX : GP2S24)

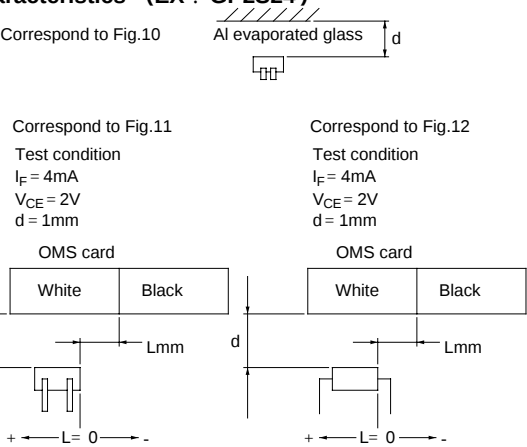


Fig.13-a Frequency Response

(GP2S09)

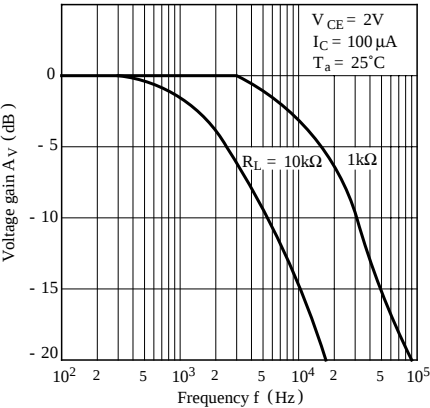


Fig.13-b Frequency Response

(GP2S24/ GP2S26/ GP2S27)

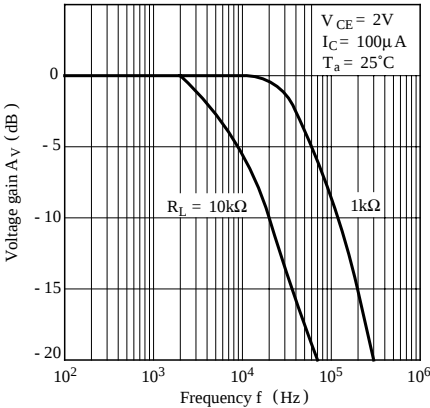
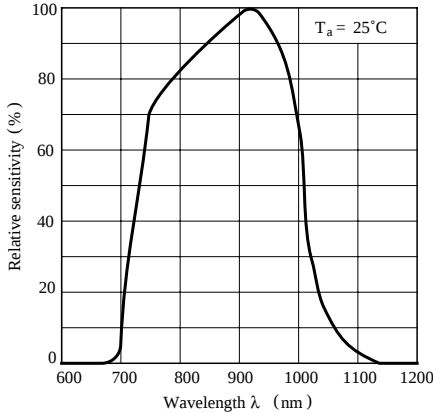


Fig.14 Spectral Sensitivity (Detecting Side)



- Please refer to the chapter “Precautions for Use”.